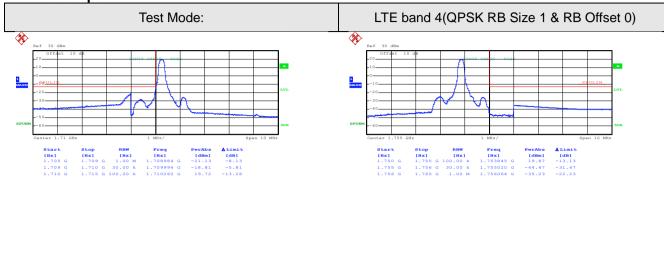




Band edge emission:

LTE band 4 part:1.4MHz:

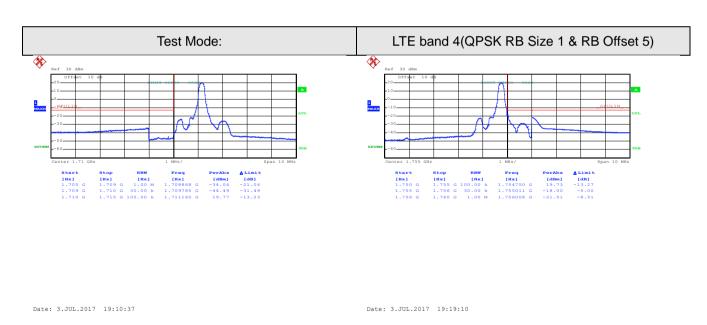


Lowest channe

Date: 3.JUL.2017 19:09:43

Date: 3.JUL.2017 19:17:20

Lowest channel Highest channel

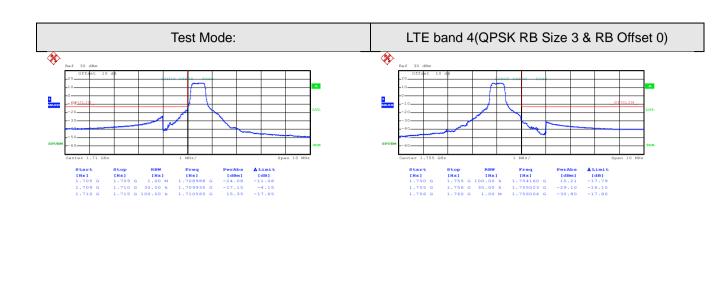


Lowest channel

Highest channel



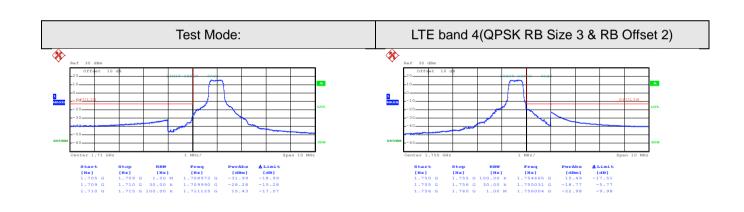




Lowest channel

Date: 3.JUL.2017 19:11:10

Highest channel



Date: 3.JUL.2017 19:11:39

Date: 3.JUL.2017 19:20:07

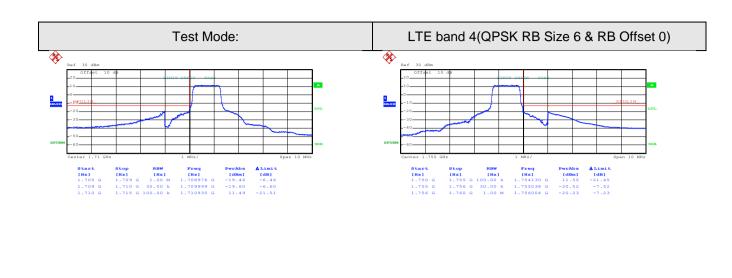
Date: 3.JUL.2017 19:19:41

Lowest channel

Highest channel



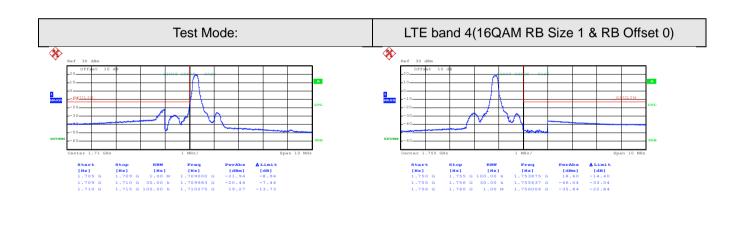




Date: 3.JUL.2017 19:12:07

Date: 3.JUL.2017 19:20:33

Lowest channel Highest channel



Date: 3.JUL.2017 19:10:03

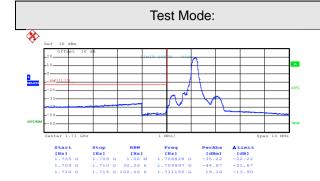
Date: 3.JUL.2017 19:18:48

Lowest channel

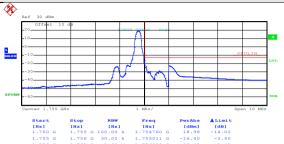
Highest channel







LTE band 4(16QAM RB Size 1 & RB Offset 5)

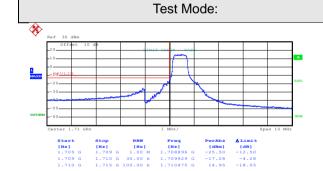


Date: 3.JUL.2017 19:10:50

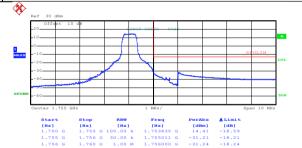
Date: 3.JUL.2017 19:19:24

Lowest channel

Highest channel



LTE band 4(16QAM RB Size 3 & RB Offset 0)



Date: 3.JUL.2017 19:11:22

Date: 3.JUL.2017 19:19:52

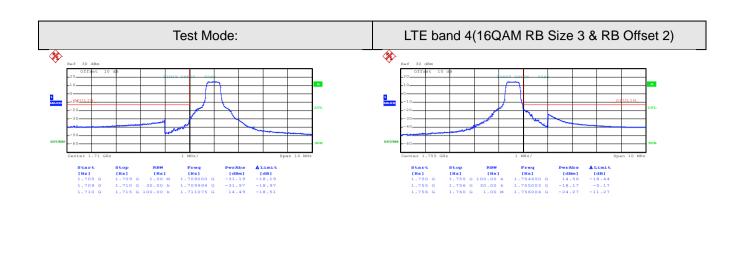
Lowest channel

Highest channel



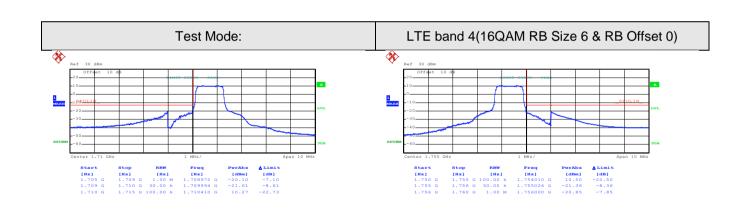


Date: 3.JUL.2017 19:11:51



Lowest channel

Highest channel



Date: 3.JUL.2017 19:12:17

Date: 3.JUL.2017 19:20:42

Date: 3.JUL.2017 19:20:19

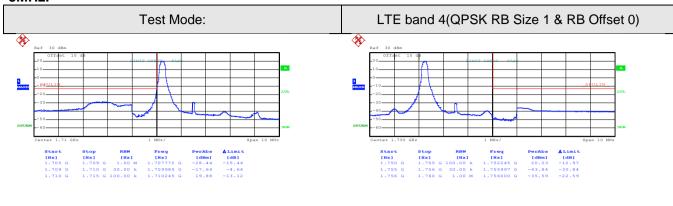
Lowest channel

Highest channel





3MHz:

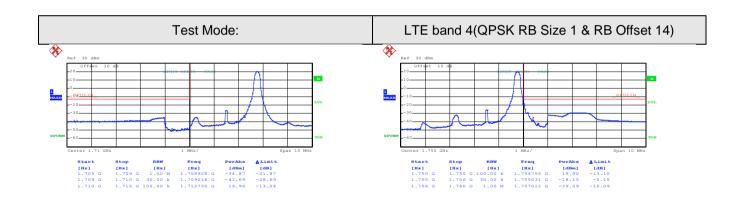


Date: 3.JUL.2017 19:22:56

Date: 3.JUL.2017 19:25:13

Lowest channel

Highest channel



Date: 3.JUL.2017 19:23:18

Date: 3.JUL.2017 19:27:15

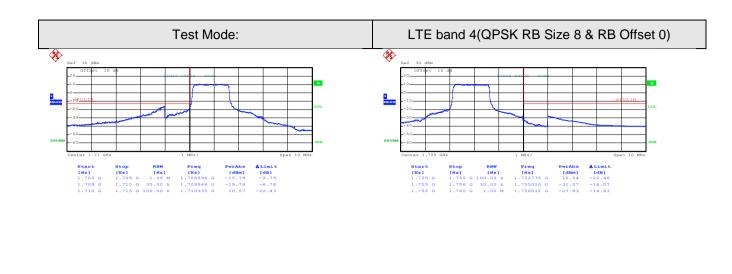
Lowest channel

Highest channel



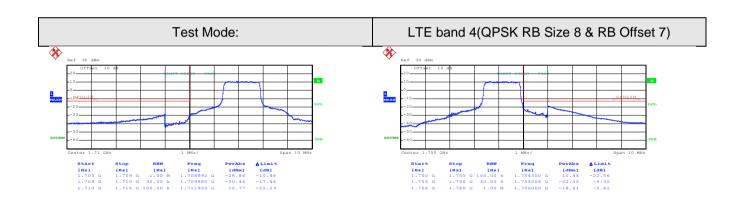


Date: 3.JUL.2017 19:23:53



Lowest channel

Highest channel



Date: 3.JUL.2017 19:24:18

Date: 3.JUL.2017 19:28:25

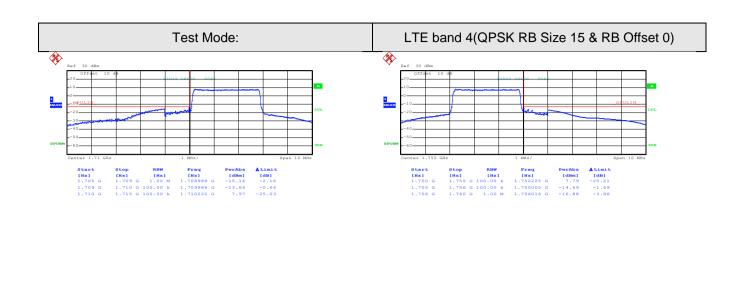
Date: 3.JUL.2017 19:27:56

Lowest channel

Highest channel



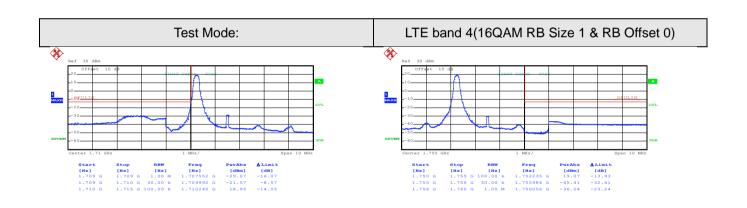




Lowest channel

Date: 3.JUL.2017 19:32:38

Highest channel



Date: 3.JUL.2017 19:23:05

Date: 3.JUL.2017 19:25:23

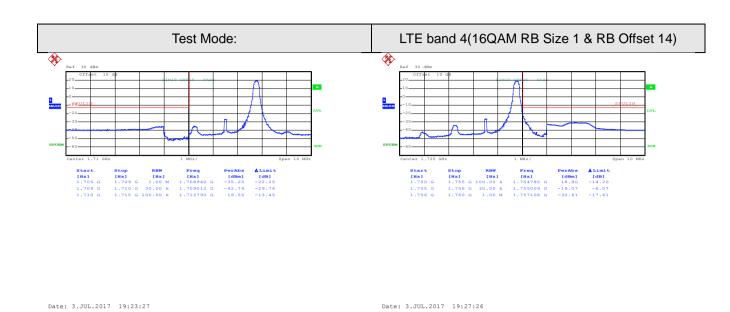
Date: 3.JUL.2017 19:32:00

Lowest channel

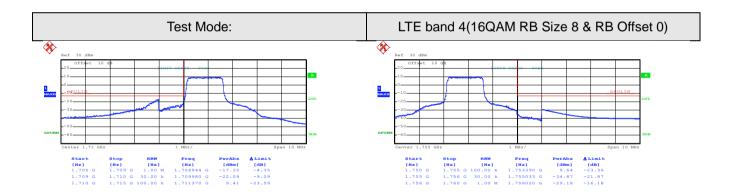
Highest channel







Lowest channel



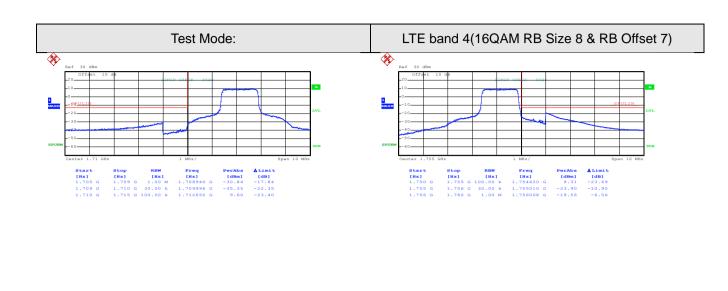
Date: 3.JUL.2017 19:24:01 Date: 3.JUL.2017 19:28:09

Lowest channel Highest channel





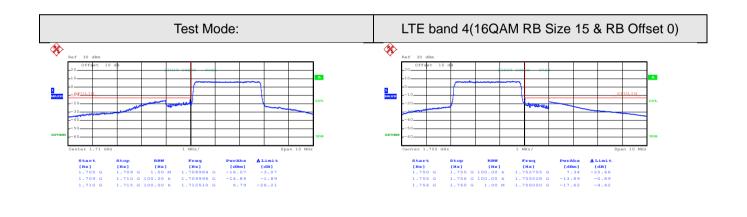
Date: 3.JUL.2017 19:24:32



Lowest channel

Highest channel

Date: 3.JUL.2017 19:28:37



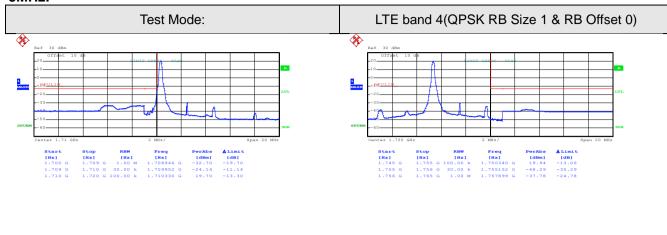
Date: 3.JUL.2017 19:32:49 Date: 3.JUL.2017 19:32:10

> Lowest channel Highest channel





5MHz:

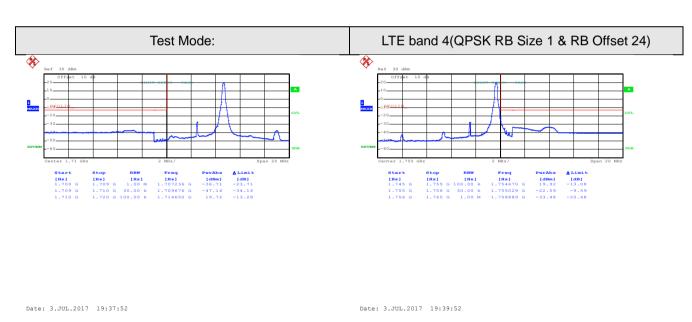


Date: 3.JUL.2017 19:37:26

Date: 3.JUL.2017 19:39:25

Lowest channel

Highest channel



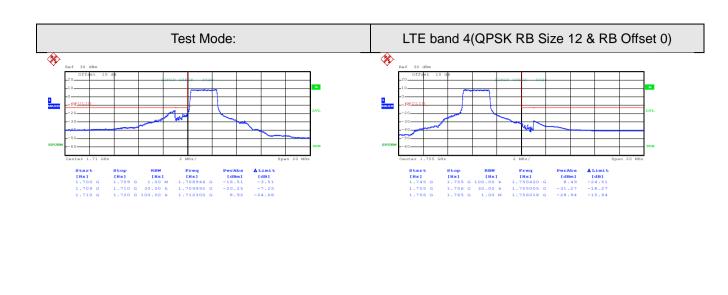
Lowest channel

Highest channel



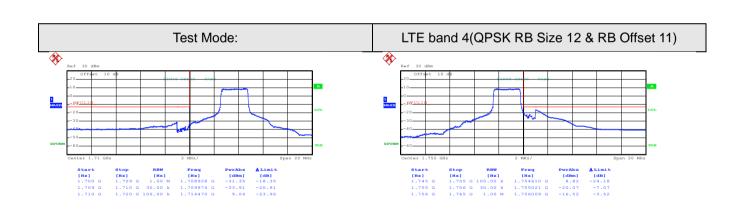


Date: 3.JUL.2017 19:38:19



Lowest channel

Highest channel



Date: 3.JUL.2017 19:38:41

Date: 3.JUL.2017 19:40:52

Date: 3.JUL.2017 19:40:20

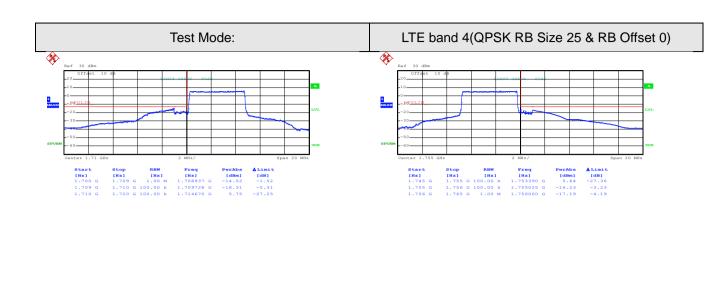
Lowest channel

Highest channel



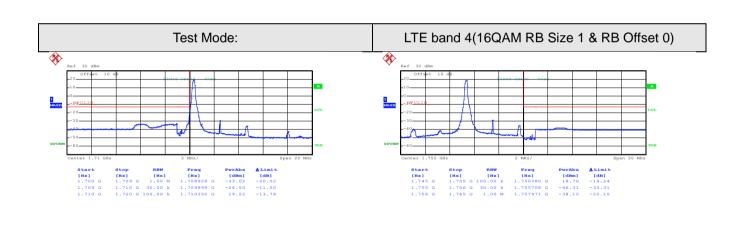


Date: 3.JUL.2017 19:34:25



Lowest channel Highest channel

Date: 3.JUL.2017 19:36:28



Date: 3.JUL.2017 19:37:37

Date: 3.JUL.2017 19:39:35

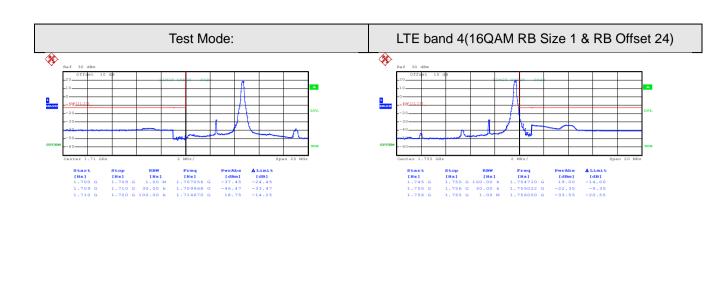
Lowest channel

Highest channel



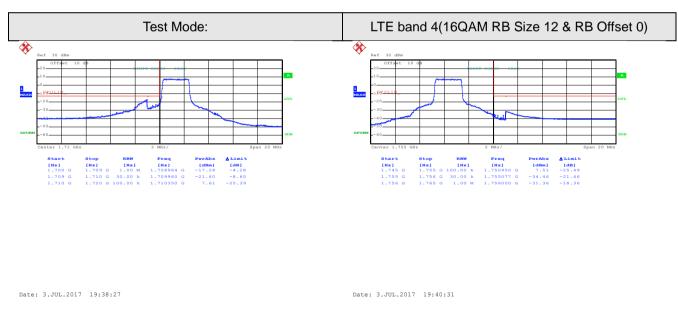


Date: 3.JUL.2017 19:38:02



Lowest channel Highest channel

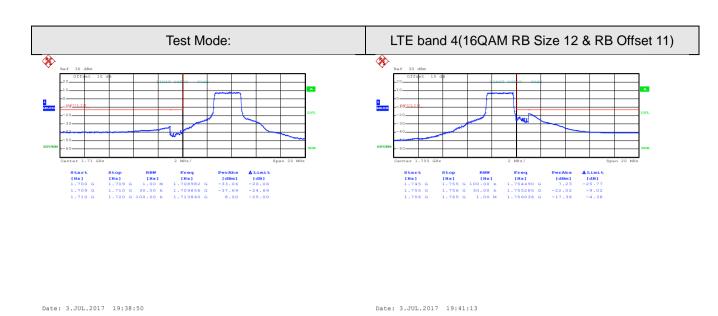
Date: 3.JUL.2017 19:40:04



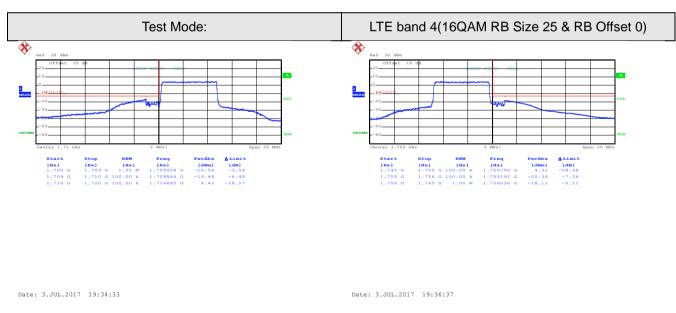
Lowest channel Highest channel







Lowest channel Highest channel

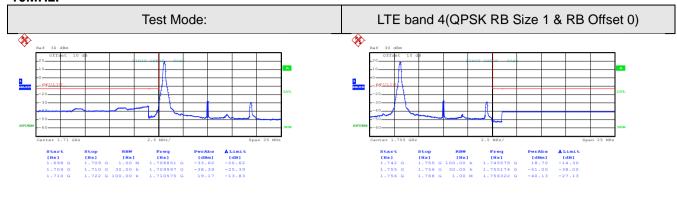


Lowest channel Highest channel





10MHz:

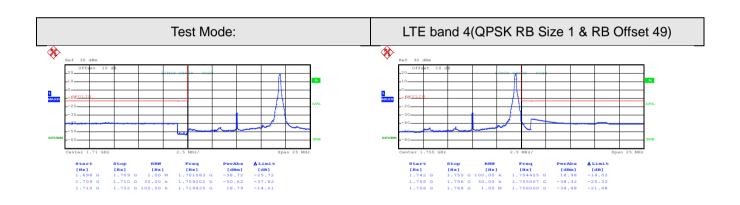


Date: 4.JUL.2017 10:54:06

Date: 4.JUL.2017 10:55:41

Lowest channel

Highest channel



Date: 4.JUL.2017 10:54:52

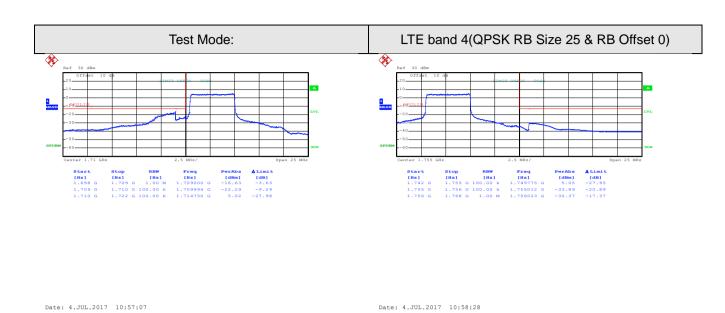
Date: 4.JUL.2017 10:56:05

Lowest channel

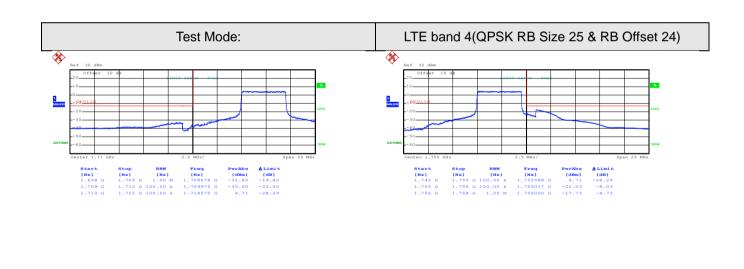
Highest channel







Lowest channel Highest channel

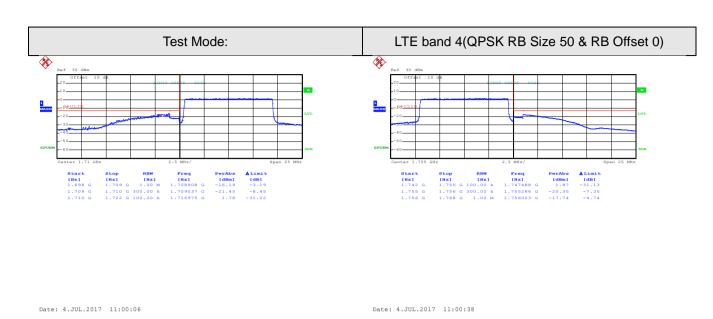


Date: 4.JUL.2017 10:57:49 Date: 4.JUL.2017 10:59:08

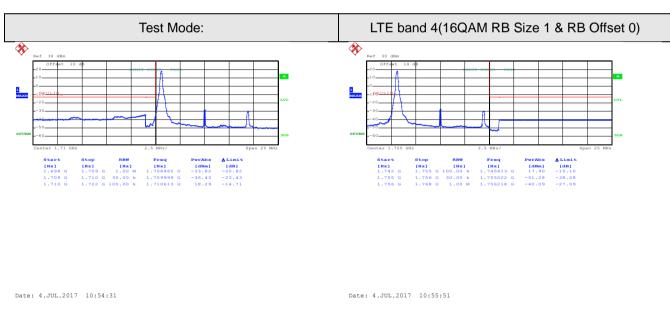
Lowest channel Highest channel







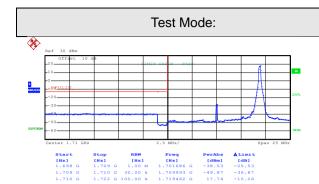
Lowest channel Highest channel



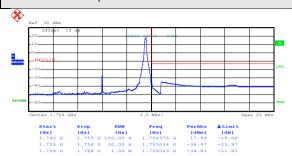
Lowest channel Highest channel







LTE band 4(16QAM RB Size 1 & RB Offset 49)

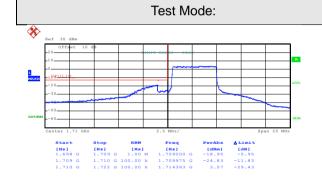


Date: 4.JUL.2017 10:55:01

Date: 4.JUL.2017 10:56:15

Lowest channel

Highest channel





Date: 4.JUL.2017 10:57:37

Date: 4.JUL.2017 10:58:42

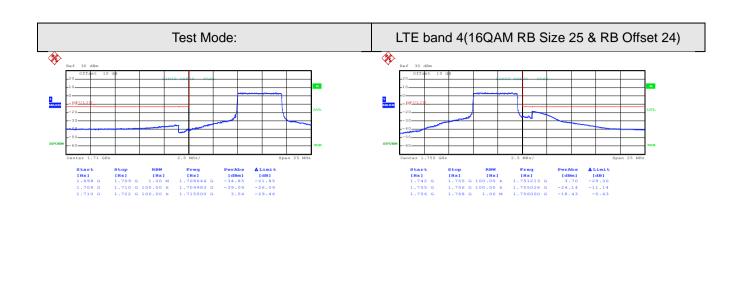
Lowest channel

Highest channel



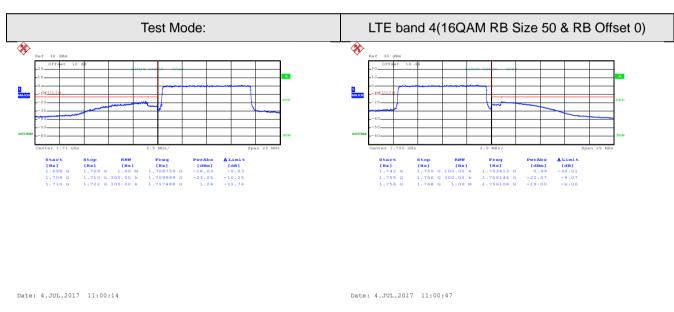


Date: 4.JUL.2017 10:57:59



Date: 4.JUL.2017 10:59:23

Lowest channel Highest channel

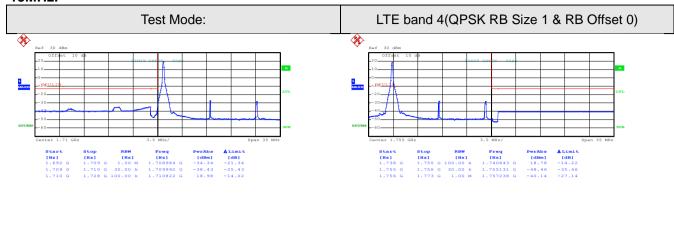


Lowest channel Highest channel





15MHz:

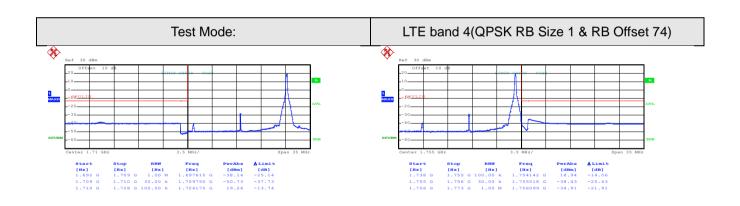


Date: 4.JUL.2017 11:03:01

Date: 4.JUL.2017 11:04:27

Lowest channel

Highest channel



Date: 4.JUL.2017 11:03:33

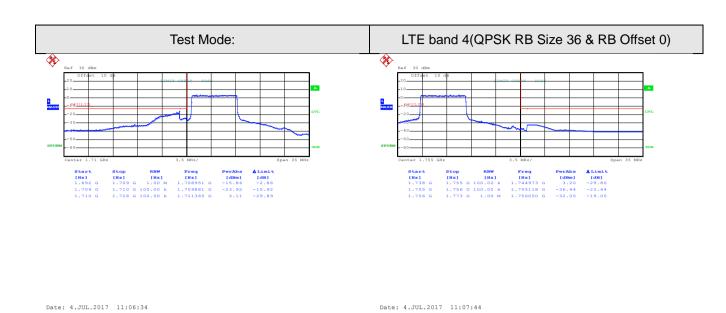
Date: 4.JUL.2017 11:04:54

Lowest channel

Highest channel

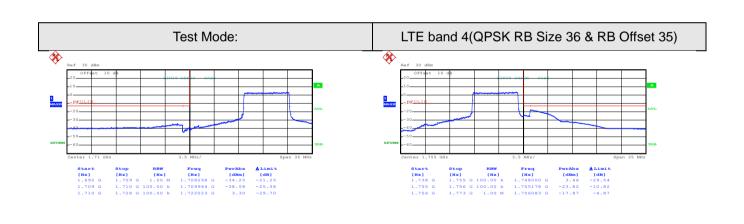






Lowest channel

Highest channel



Date: 4.JUL.2017 11:07:02

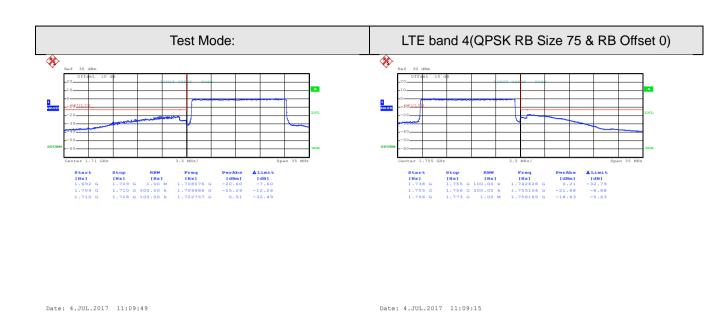
Date: 4.JUL.2017 11:08:09

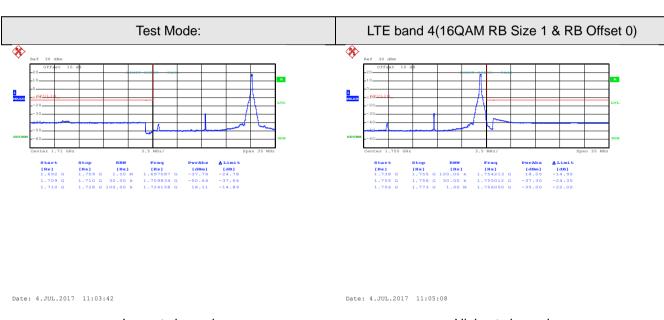
Lowest channel

Highest channel







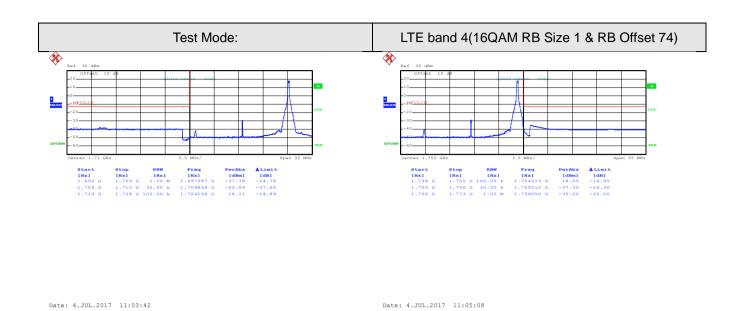


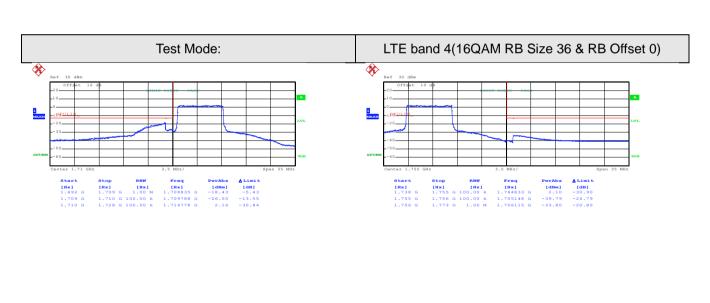
Lowest channel Highest channel

Lowest channel









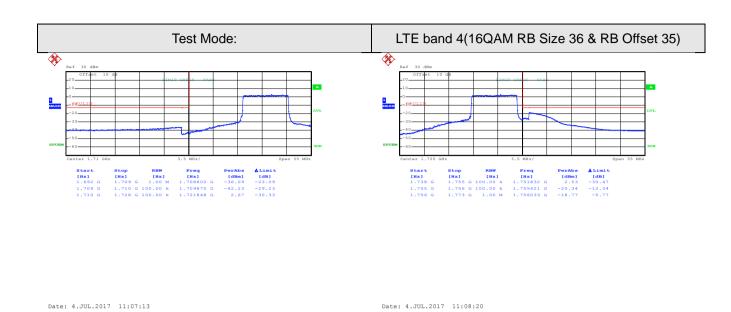
Date: 4.JUL.2017 11:06:44 Date: 4.JUL.2017 11:07:54

Lowest channel Highest channel

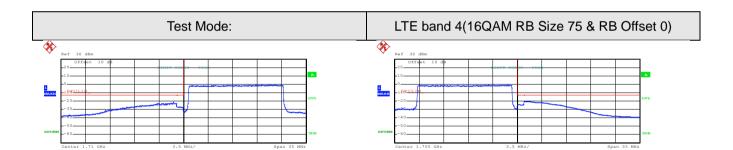
Lowest channel







Lowest channel



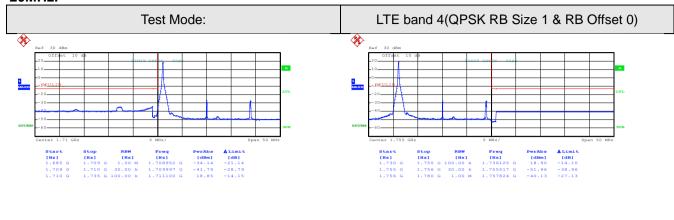
Date: 4.JUL.2017 11:09:57 Date: 4.JUL.2017 11:09:27

Lowest channel Highest channel





20MHz:

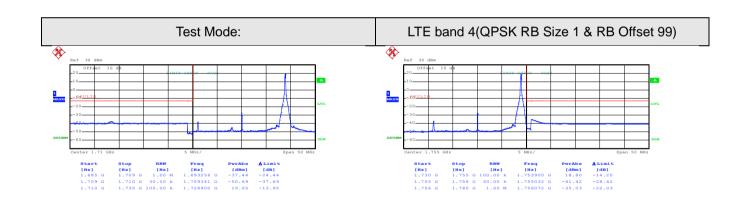


Date: 4.JUL.2017 11:15:39

Date: 4.JUL.2017 11:14:36

Lowest channel

Highest channel



Date: 4.JUL.2017 11:16:00

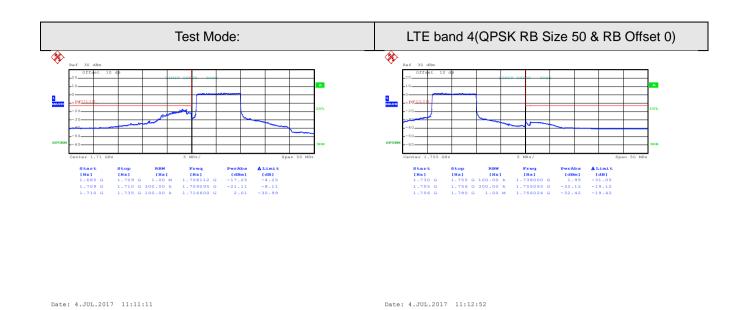
Date: 4.JUL.2017 11:14:59

Lowest channel

Highest channel

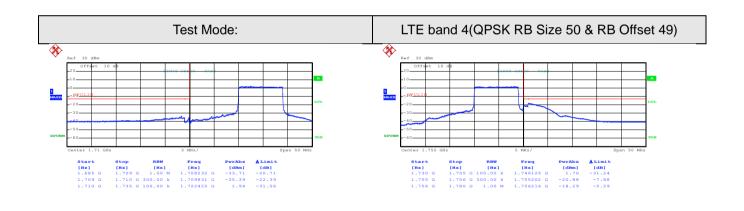






Lowest channel

Highest channel



Date: 4.JUL.2017 11:11:39

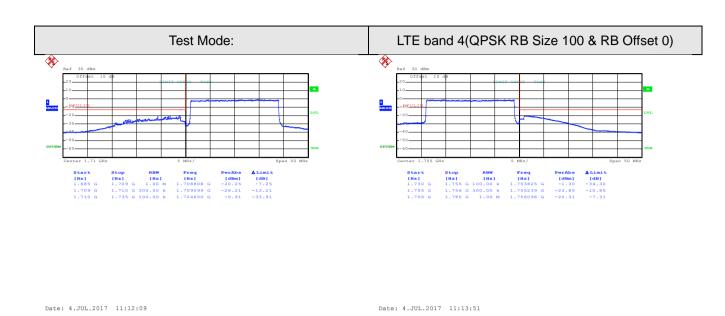
Date: 4.JUL.2017 11:13:23

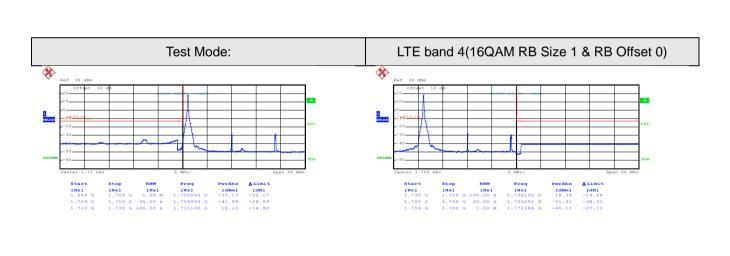
Lowest channel

Highest channel









Date: 4.JUL.2017 11:15:48

Date: 4.JUL.2017 11:14:47

Lowest channel

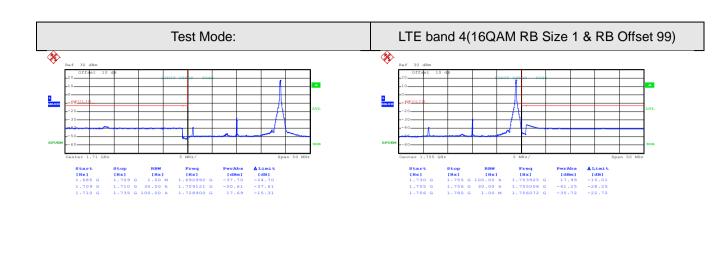
Lowest channel

Highest channel

Highest channel



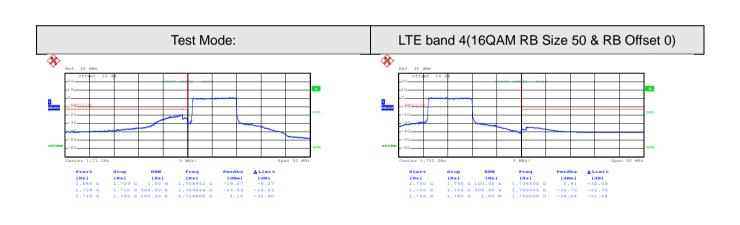




Lowest channel

Date: 4.JUL.2017 11:16:09

Highest channel



Date: 4.JUL.2017 11:11:25

Date: 4.JUL.2017 11:13:07

Date: 4.JUL.2017 11:15:10

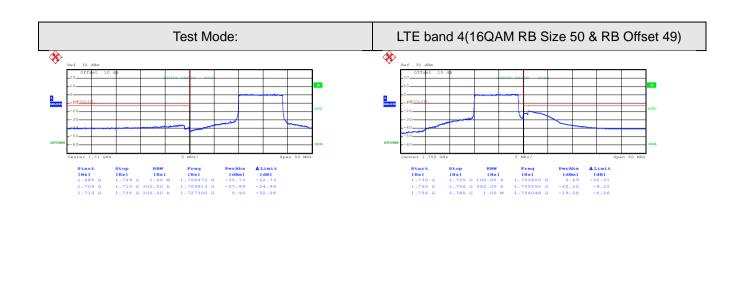
Lowest channel

Highest channel



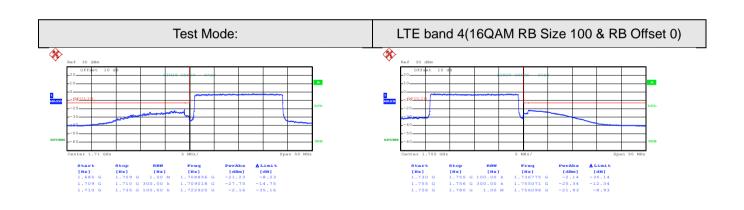


Date: 4.JUL.2017 11:11:52



Lowest channel

Highest channel



Date: 4.JUL.2017 11:12:17

Date: 4.JUL.2017 11:14:00

Date: 4.JUL.2017 11:13:37

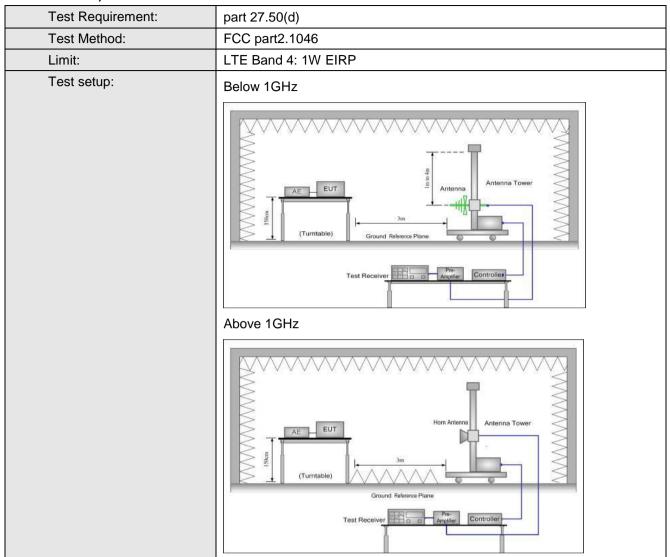
Lowest channel

Highest channel





6.10 ERP, EIRP Measurement







	·
Test Procedure:	1. The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer.
	2. During the measurement, the EUT was communication with the station. The highest emission was recorded with the rotation of the turntable and the lowering of the test antenna from 4m to 1m. The reading was recorded and the field strength (E in dBuV/m) was calculated.
	3. ERP in frequency band below 1GHz were measured using a substitution method. The EUT was replaced by dipole antenna connected, the S.G. output was recorded and ERP was calculated as follows:
	ERP = S.G. output (dBm) + Antenna Gain (dBd) – Cable Loss (dB)
	4. EIRP in frequency band above 1GHz were measured using a substitution method. The EUT was replaced by or horn antenna connected, the S.G. output was recorded and EIRP was calculated as follows:
	EIRP = S.G. output (dBm) + Antenna Gain (dBi) - Cable Loss (dB)
	5. The worse case was relating to the conducted output power.
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed





Measurement Data (worst case):

LTE band 4 part

Lowest channel

Frequency (MHz)	UL Channel	Modulation	BW (MHz)	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result				
	1.4MHz(RB size 1 & RB offset 0)											
1710.70	19957	QPSK	1.4	Н	V	22.13						
1710.70	19937	QFSK	1.4	П	Н	21.25	30.00	Pass				
1710.70	10057	16QAM	1.4	Н	V	22.20	30.00	Fa55				
1710.70	19957	IOQAW	1.4	П	Н	20.92	I					
		•	I.4MHz(RE	3 size 3 &	RB offset 0)							
1710 70	40057	ODSK 1.4	ODSK 4	ODCK	4.4	4.4	4.4	Н	V	22.21		
1710.70	19957	QPSK	1.4	П	Н	20.99	30.00	Pass				
1710.70	19957	16QAM	1.4	Н	V	22.14	30.00	Fa55				
1710.70	19957	IOQAW	1.4	П	Н	20.97						
		•	1.4MHz(RE	3 size 6 &	RB offset 0)							
4740.70	10057	ODCK	4.4	1.1	V	21.78						
1710.70	19957	QPSK	1.4 H		Н	20.67	20.00	Door				
1710.70	10057	16QAM	1.4	Н	V	21.64	30.00	Pass				
1710.70	19957	IOQAW	1.4	П	Н	20.77						

Middle channel

	Wildlie Chaintei													
Frequency (MHz)	UL Channel	Modulation	BW (MHz)	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result						
		1	.4MHz(RE	3 size 1 &	RB offset 0)									
1732.50	20175	QPSK	1.4	Н	V	22.24								
1732.50	20173	QFSK	1.4	П	Н	21.31	30.00	Pass						
1732.50	20175	16O A M	1.4	Н	V	22.16	30.00	Fa55						
1732.30	20173	16QAM	1.4	- 11	Н	21.03		1						
		1	.4MHz(RE	3 size 3 &	RB offset 0)									
1732.50	20175	20175	20175	20175	20175	20175	QPSK	K 1.4	1.4	Н	V	22.30		1
1732.50	20175	QFSK	1.4	- 11	Н	21.12	30.00	Pass						
1732.50	20175	16QAM	1.4	Н	V	22.11	30.00	rass						
1732.30	20173	TOQAM	1.4	1.4	1.1	Н	20.92							
	1.4MHz(RB size 6 & RB offset 0)													
1732.50	20175	QPSK	1.4	Н	V	21.75								
1732.50	20173	QF3N	1.4	1.4	1.4	1.4	1.4	П	Н	20.72	30.00	Page		
1732.50	20175	16QAM 1.4		1.4 H	V	21.53	30.00	Pass						
1732.50	20175	TOQAM	1.4	11	Н	20.85								





Frequency (MHz)	UL Channel	Modulation	BW (MHz)	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result							
			1.4MHz(RE	size 1 & F	RB offset 0)										
1754.30	20393	QPSK	1.4	Н	V	22.15									
1754.50	20393	QFSK	1.4	П	Н	21.26	30.00	Pass							
1754.30	20393	16O A M	1 1	ы	V	22.25	30.00	Fa55							
1754.50	20393	16QAM	1.4 H	П	Н	21.10									
			1.4MHz(RE	3 size 3 & F	RB offset 0)										
1751 20	20202	20202	20202	20202	20202	20202	20202	20202	ODSK	116	Н	V	22.21		
1754.30	20393	QPSK	1.4	П	Н	21.23	30.00	Pass							
1754.30	20393	16O A M	1 1	Н	V	22.33	30.00	Fa55							
1754.50	20393	16QAM	1.4	1.4	1.4	П	Н	20.96							
		,	1.4MHz(RE	3 size 6 & F	RB offset 0)										
4754.00	20202	ODCK	4.4	- 11	V	21.58									
1754.30	20393	QPSK	1.4	Н	Н	20.65	20.00	Door							
1751 20	20202	160 A M	1.4	Н	V	21.45	30.00	Pass							
1754.30	20393	16QAM	1.4	П	Н	20.81									

Lowest channel

Frequency (MHz)	UL Channel	Modulation	BW (MHz)	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		2	0MHz(RB si	ze 1 & RB	offset 0)			
1720.00	20050	OBSK	20	Н	V	22.81		
1720.00	20050	QPSK	20	Г	Н	22.80	20.00	Door
1720.00	20050	16QAM	20	Н	V	22.64	30.00	Pass
1720.00	20030	IOQAW	20	П	Н	23.01		
		20MHz	(RB size 50	& RB offse	et 0)			
1720.00	20050	QPSK	20	Н	V	20.96		
1720.00	20050	QFSK	20	П	Н	21.47	30.00	Pass
1720.00	20050	16QAM	20	Н	V	21.36	30.00	F a 5 5
1720.00	20030	TOQAIVI	20	11	Н	21.92		
	20MHz(RB size 100 & RB offset 0)							
1720.00	20050	QPSK	20	Н	V	20.43		
1720.00	20030	QF 5K	20		Н	20.93	30.00	Pass
1720.00	20050	16QAM	20	Н	V	21.40	30.00	F a 5 5
1720.00	20050	IOQAW	20	П	Н	20.91		



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Middle channel

Frequency (MHz)	UL Channel	Modulation	BW (MHz)	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		2	0MHz(RB si	ze 1 & RB	offset 0)			
1722.50	20175	ODSK	20	Ш	V	22.76		
1732.50	20175	QPSK	20	Н	Н	22.84	30.00	Pass
1722.50	20175	16O A M	20	Н	V	22.69	30.00	Fa55
1732.50	20175	16QAM	20	П	Н	22.83		
		20	MHz(RB siz	ze 50 & RE	3 offset 0)			
1722 FO	20175	ODSK	20	Н	V	21.10		
1732.50	20175	QPSK	20	П	Н	21.54	20.00	Pass
1732.50	20175	16QAM	20	Н	V	21.35	30.00	F 455
1732.50	20175	TOQAM	20	П	Н	21.89		
	20MHz(RB size 100 & RB offset 0)							
1732.50	20175	QPSK	20	Н	V	20.55		
1732.50	20175	QFSN	20	П	Н	20.87	20.00	Door
1732.50	20175	16QAM	20	Н	V	21.35	30.00	Pass
1732.50	20173	TOQAM	20	П	Н	20.97		

High channe

High channel																										
Frequency (MHz)	UL Channel	Modulation	BW (MHz)	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result																		
			20MHz(RB si	ze 1 & RB	offset 0)																					
1745.00	20300	QPSK	20	Н	V	22.84																				
1745.00	20300	QFSK	20	П	Н	22.79	30.00	Pass																		
1745.00	20300	16QAM	20	Н	V	22.78	30.00	F a 5 5																		
1745.00	20300	TOQAM	20	!!	Н	22.72																				
		:	20MHz(RB siz	ze 50 & RE	offset 0)																					
1745.00	20300	QPSK	20	Н	V	21.02																				
1745.00	20300	QFSK	20	П	Н	21.41	30.00	Pass																		
1745.00	20300	16QAM	20	Н	V	21.47	30.00	F a 5 5																		
1745.00	20300	20300	5.00 20300	+5.00 20300	20300	20300	20300	20300	20300	20300	20300	20300	20300	20300	20300	20300	20300	IOQAW	IOQAW	20	20	Н	Н	21.85		
	20MHz(RB size 100 & RB offset 0)																									
1745.00	20300	QPSK	20	Н	V	20.63																				
1745.00	20300	QFSN	20	П	Н	20.82	30.00	Pass																		
1745.00	20300	16QAM	20	Н	V	21.47	50.00	F a 5 5																		
1745.00	20300	IOQAW	20	11	Η	21.13																				



6.11 Field strength of spurious radiation measurement

	urious radiation measurement
Test Requirement:	Part 27.53(h)
Test Method:	FCC part2.1053
Limit:	LTE Band 4-13dBm
Test setup:	Below 1GHz Antenna Tower Ground Reference Plane Above 1GHz
	Horn Antenna Tower (Turntable) Ground Reference Plane Test Receiver Test Receiver Controller
Test Procedure:	 The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) – Cable Loss (dB)
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details.
Test results:	Passed



Measurement Data (worst case):

Below 1GHz:

The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

Above 1GHz

For above 1 GHz, all test modes were performed, just the worst case shown in the report.

LTE Band 4 Part:

	1.4MHz(RB siz	ze 1 & RB offset 0) fo	or QPSK	
Frequency (MHz)	Spurious I	Emission	Limit (dBm)	Result
1 requericy (Wir 12)	Polarization	Level (dBm)	Limit (abin)	Result
		Lowest		
3421.40	Vertical	-45.57		
5132.10	V	-41.98		
6842.80	V	-40.16	42.00	Door
3421.40	Horizontal	-48.73	-13.00	Pass
5132.10				
6842.80	Н	-40.38		
·		Middle		•
3465.00	Vertical	-49.36		Pass
5197.50	V	-40.43		
6930.00	V	-38.13	42.00	
3465.00	Horizontal	-45.72	-13.00	
5197.50	Н	-40.60		
6930.00	Н	-36.51		
<u> </u>		Highest		
3508.60	Vertical	-48.54		
5262.90	V	-42.45		
7017.20	V	-38.16	42.00	Door
3508.60	Horizontal	-45.90	-13.00	Pass
5262.90	Н	-40.23		
7017.20	Н	-37.04		





3MHz(RB size 1 & RB offset 0) for QPSK						
Fragues av (MIII-)		Emission		Desult		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result		
Lowest						
3423.00	Vertical	-49.68				
5134.50	V	-42.35				
6846.00	V	-41.22	42.00	Pass		
3423.00	Horizontal	-13.00				
5134.50	Н	-38.47				
6846.00	Н	-40.75]			
·		Middle		·		
3465.00	Vertical	-50.24				
5197.50	V	-41.26				
6930.00	V	-40.75	-13.00	Door		
3465.00	Horizontal	-47.42	-13.00	Pass		
5197.50	Н	-42.36				
6930.00	Н	-38.77				
		Highest				
3507.00	Vertical	-51.22				
5260.50	V	-43.69				
7014.00	V	-39.63	12.00	Pass		
3507.00	Horizontal	-47.15	-13.00	Pass		
5260.50	Н	-43.30				
7014.00	Н	-37.89				





	FMU-/DD at	4 0 DD -fft 0\ f	Sam ODCI/	
		ze 1 & RB offset 0) f	or QPSK	
Frequency (MHz)	Polarization	Emission Level (dBm)	Limit (dBm)	Result
	1 Olalization	Lowest		
3425.00	Vertical	-47.23		
5137.50	Vertical	-42.15		
6850.00	V	-40.36		
	v Horizontal		-13.00	Pass
3425.00		-49.86		
5137.50	Н	-39.34		
6850.00	Н	-40.23		
		Middle		
3465.00	Vertical	-50.23		Pass
5197.50	V	-41.36		
6930.00	V	-40.74	42.00	
3465.00	Horizontal	-46.33	-13.00	
5197.50	Н	-41.58		
6930.00	Н	-38.54		
		Highest		
3505.00	Vertical	-49.63		
5257.50	V	-42.15		
7010.00	V	-39.55	-13.00	Pass
3505.00	Horizontal	-46.33	-13.00	rass
5257.50	Н	-41.25		
7010.00	Н	-38.57		





	10MHz(RB si	ze 1 & RB offset 0) f	or QPSK		
Fraguenov (MHz)	Spurious			Result	
Frequency (MHz)	Polarization Level (Limit (dBm)	Result	
		Lowest			
3430.00	Vertical	-49.78			
5145.00	V	-41.52			
6860.00	V -40.73		-13.00	Pass	
3430.00	Horizontal	-49.58	-13.00	Pass	
5145.00	Н	-39.63			
6860.00	Н	H -41.22			
Middle					
3465.00	Vertical	-51.47			
5197.50	V	-41.69			
6930.00	V	-41.55	-13.00	Pass	
3465.00	Horizontal	-45.78	-13.00		
5197.50	Н	-41.27			
6930.00	Н	-39.56			
		Highest			
3500.00	Vertical	-53.26			
5250.00	V	-41.02			
7000.00	V	-38.67	-13.00	Pass	
3500.00	Horizontal	-46.39	-13.00	Pass	
5250.00	Н	-41.72			
7000.00	Н	-38.57			





15MHz(RB size 1 & RB offset 0) for QPSK					
Fraguency (MUz)		Emission		Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
		Lowest			
3435.00	Vertical	-46.59			
5152.50	V	-41.58			
6870.00	V -39.87		12.00	Door	
3435.00	Horizontal	-48.69	-13.00	Pass	
5152.50	Н	-39.85			
6870.00	Н	-41.23			
	Middle				
3465.00	Vertical	-51.24			
5197.50	V	-42.12			
6930.00	V	-40.57	40.00	Dana	
3465.00	Horizontal	-47.52	-13.00	Pass	
5197.50	Н	-43.26			
6930.00	Н	-37.69			
		Highest			
3495.00	Vertical	-50.42			
5242.50	V	-42.71			
6990.00	V	-38.69	-13.00	Pass	
3495.00	Horizontal	-46.28	-13.00	F d 5 5	
5242.50	Н	-42.13			
6990.00	Н	-39.45			





	20MHz/PR e	ize 1 & RB offset 0) for OPSK	
		Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
Lowest				
3440.00	Vertical	-50.36		
5160.00	V	-41.71		
6880.00	V			Dana
3440.00	Horizontal	-50.99	-13.00	Pass
5160.00	Н	-40.88		
6880.00	Н	-40.82		
	<u> </u>	Middle		
3465.00	Vertical	-51.17		
5197.50	V	V -41.26		
6930.00	V	-41.05	-13.00	Pass
3465.00	Horizontal	-47.92	-13.00	
5197.50	Н	-42.43		
6930.00	Н	-41.35		
		Highest		
3490.00	Vertical	-52.03		
5235.00	V	-43.42		
6980.00	V	-40.70	12.00	Door
3490.00	Horizontal	-47.82	-13.00	Pass
5235.00	Н	-42.25		
6980.00	Н	-39.51		



6.12 Frequency stability V.S. Temperature measurement

Test Requirement:	Part 24.235, Part 27.54, Part 2.1055(a)(1)(b)
Test Method:	FCC Part2.1055(a)(1)(b)
Limit:	±2.5ppm
Test setup:	Spectrum analyzer EUT Att. Variable Power Supply
	Note: Measurement setup for testing on Antenna connector
Test procedure:	 The equipment under test was connected to an external DC power supply and input rated voltage. RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators. The EUT was placed inside the temperature chamber. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency. Turn EUT off and set the chamber temperature to −30°C. After the temperature stabilized for approximately 30 minutes recorded the frequency. Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed
Remark:	All three channels of all modulations have been tested, but only the worst channel and the worst modulation show in this test item.

Measurement Data (the worst channel):





LTE Band 4(QPSK):

Reference Fr	equency: LTE Band	4(1.4MHz) N	Middle channel=20175	channel=1732.50)MHz
Power supplied	Temperature (°C)	Frequency error		Limit (ppm)	Result
(Vdc)	Temperature (©)	Hz	ppm	Еши (ррш)	Result
	-30	194	0.111977		
	-20	121	0.069841		
	-10	145	0.083694		
	0	179	0.103319		
3.80	10	158	0.091198	±2.5	Pass
0.00	20	149	0.086003		1 400
	30	130	0.075036		
	40	105	0.060606		
	50	116	0.066955		
Reference F	requency: LTE Band		iddle channel=20175 c	hannel=1732.50	MHz
Power supplied	Temperature (°ℂ)	Fr	equency error	Limit (ppm)	Result
(Vdc)	remperature (C)	Hz	ppm	Limit (ppin)	Resuit
	-30	154	0.088889		Pass
	-20	121	0.069841		
	-10	132	0.076190		
	0	172	0.099278	±2.5	
3.80	10	144	0.083117		
0.00	20	126	0.072727		
	30	148	0.085426		
	40	106	0.061183		
	50	115	0.066378		
Reference F	requency: LTE Band		iddle channel=20175 c	hannel=1732.50	MHz
	- (%)	Frequency error			- I
Power supplied (Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	163	0.094084		
	-20	121	0.069841		
	-10	132	0.076190	_	
	0	126	0.072727	_	
3.80	10	169	0.097547	±2.5	Pass
	20	146	0.084271		
	30	106	0.061183	_	
	40	153	0.088312	_	
	50	148	0.085426		





Reference Fr	equency: LTE Band	4(10MHz) N	/liddle channel=20175	channel=1732.50)MHz
Power supplied (Vdc)	Temperature (°C)	Frequency error		Limit (ppm)	Result
rower supplied (vac)	remperature (C)	Hz	ppm	Limit (ppin)	Kesuit
	-30	166	0.095815		
	-20	169	0.097547		
	-10	150	0.086580		
	0	130	0.075036		
3.80	10	102	0.058874	±2.5	Pass
	20	142	0.081962		
	30	146	0.084271		
	40	127	0.073304		
	50	116	0.066955		
Reference Fr	equency: LTE Band		/liddle channel=20175	channel=1732.50	MHz
Power supplied (Vdc)	Temperature (°C)		equency error	Limit (ppm)	Result
	• • • • •	Hz	ppm	(PP···)	Kesuit
	-30	150	0.086580		
	-20	160	0.092352		Pass
	-10	130	0.075036		
	0	136	0.078499		
3.80	10	142	0.081962	±2.5	
	20	158	0.091198	1	
	30	169	0.097547	7	
	40	103	0.059452	1	
	50	116	0.066955		
Reference Fr	equency: LTE Band	4(20MHz) N	liddle channel=20175	channel=1732.50	MHz
Dower oundied (\/de\)	Tomporature (°C)	Fr	equency error	Limit (nnm)	
Power supplied (Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	196	0.113131		
	-20	121	0.069841		
	-10	163	0.094084		
	0	169	0.097547		
3.80	10	178	0.102742	±2.5	Pass
	20	142	0.081962		. 400
	30	148	0.085426		
	40	156	0.090043		
	50	106	0.061183	7	





LTE Band 4(16QAM):

LTE Band 4(16QAM):					
Reference F	requency: LTE Band	4(1.4MHz)	Middle channel=20175	channel=1732.5	0MHz
	Temperature (°C)	Fi	requency error	Limit (nnm)	
Power supplied (Vdc)	remperature (C)	Hz	ppm	Limit (ppm)	Result
	-30	121	0.069841		
	-20	148	0.085426		
	-10	142	0.081962		
	0	124	0.071573		
3.80	10	153	0.088312	±2.5	Pass
0.00	20	136	0.078499		. 466
	30	129	0.074459		
	40	146	0.084271		
	50	107	0.061760		
Reference F			iddle channel=20175	rhannel-1732 50	MHz
TOTOTOTIC 1	requeriey. ETE Baria	, ,			VIII 12
Power supplied (Vdc)	Temperature (°C)	Frequency error		Limit (ppm)	Result
Power supplied (vac)		Hz	ppm	- (FF /	Resuit
	-30	162	0.093506		
	-20	121	0.069841		Pass
	-10	136	0.078499		
	0	128	0.073882		
3.80	10	164	0.094661	±2.5	
	20	158	0.091198		
	30	153	0.088312		
	40	156	0.090043		
	50	147	0.084848		
Reference F	requency: LTE Band	4(5MHz) M	iddle channel=20175	channel=1732.50	MHz
Davisa averalia d (V/da)	Tamanaratura (°C)	Frequency error		Lineit (mmm)	Danult
Power supplied (Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	156	0.090043		
	-20	160	0.092352		
	-10	130	0.075036	4	
	0	142	0.081962		
3.80	10	169	0.097547	±2.5	Pass
	20	121	0.069841	4	
	30	136	0.078499	4	
	40	127	0.073304	-	
	50	116	0.066955		





D	Tomanaustinia (°C)	Frequency error		Limit ()	·
Power supplied (Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	163	0.094084		
	-20	121	0.069841		
	-10	133	0.076768		
	0	142	0.081962		
3.80	10	166	0.095815	±2.5	Pass
	20	158	0.091198		
	30	153	0.088312		
	40	148	0.085426		
	50	107	0.061760		
	requency: LTE Band			channel=1732.50	MHz
Power supplied	Temperature (°C)		quency error	Limit (ppm)	Result
(Vdc)	, , ,	Hz	ppm	(FF)	
	-30	153	0.088312		
	-20	121	0.069841		Pass
	-10	142	0.081962		
	0	146	0.084271		
3.80	10	126	0.072727	±2.5	
	20	131	0.075613		
	30	134	0.077345		
	40	103	0.059452		
	50	114	0.065801		
Reference F	requency: LTE Band	4(20MHz) M		5 channel=1732.50	MHz
Power supplied	Temperature (°ℂ)	Fre	equency error		
(Vdc)	Temperature (C)	Hz	ppm	Limit (ppm)	Result
	-30	163	0.094084		
	-20	121	0.069841		
	40	128	0.073882		
	-10	120		 I	
	-10		0.081962		
3.80	0	142	0.081962 0.085426		Page
3.80	0 10	142 148	0.085426	±2.5	Pass
3.80	0 10 20	142 148 153	0.085426 0.088312	±2.5	Pass
3.80	0 10	142 148	0.085426	±2.5	Pass



6.13 Frequency stability V.S. Voltage measurement

Test Requirement:	Part 24.235, Part 27.54, Part 2.1055(d)(2)
Test Method:	FCC Part2.1055(d)(1)(2)
Limit:	2.5ppm
Test setup:	Temperature Chamber Spectrum analyzer EUT
	Att.
	Variable Power Supply Note: Measurement setup for testing on Antenna connector
Test procedure:	 Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency. Reduce the input voltage to specify extreme voltage variation (+/-15%) and endpoint, record the maximum frequency change.
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details, and all channels have been tested, only shows the worst channel data in this report.
Test results:	Passed





Measurement Data (the worst channel):

LTE Band 4(QPSK):

		LIE Band 4(Q	ronj.		
Reference F	requency: LTE Band	4(1.4MHz) Middle	e channel=20175	channel=1732.50	MHz
Temperature ($^{\circ}\!\mathbb{C}$)	Power supplied	Freque	ncy error	12-26 (Result
	(Vdc)	Hz	ppm	Limit (ppm)	
25	4.35	88	0.050794	±2.5	Pass
	3.80	54	0.031169		
	3.14	79	0.045599		
Reference	Frequency: LTE Band	I 4(3MHz) Middle	channel=20175 c	hannel=1732.50N	ИHz
Temperature (°C)	Power supplied	Freque	ncy error	Limit (ppm)	Result
	(Vdc)	Hz	ppm		
	4.35	78	0.045022		Pass
25	3.80	43	0.024820	±2.5	
25	3.14	66	0.038095		
Reference	Frequency: LTE Band	I 4(5MHz) Middle	channel=20175 c	hannel=1732.50N	ЛНz
	Power supplied	Frequency error			
Temperature (°C)	(Vdc)	Hz	ppm	Limit (ppm)	Result
25	4.35	85	0.049062		Pass
	3.80	88	0.050794	±2.5	
	3.14	43	0.024820		
Reference F	requency: LTE Band	4(10MHz) Middle	channel=20175	channel=1732.50	MHz
Temperature (℃)	Power supplied	Freque	ncy error		Result
	(Vdc)	Hz	ppm	Limit (ppm)	
	4.35	48	0.027706	±2.5	Pass
25	3.80	79	0.045599		
	3.14	63	0.036364		
Reference F	requency: LTE Band	4(15MHz) Middle	channel=20175	channel=1732.50	MHz
	Power supplied	Freque	ncy error		
Temperature ($^{\circ}\!\!\mathbb{C}$)	Power supplied (Vdc)	Frequei Hz	ncy error ppm	Limit (ppm)	Result
Temperature (°C)	Power supplied (Vdc) 4.35	Hz	ppm	Limit (ppm)	Result
Temperature (°C)	(Vdc)	Hz 88	ppm 0.050794	Limit (ppm)	Result Pass
. , , , , , , , , , , , , , , , , , , ,	(Vdc) 4.35	Hz	ppm		
25	(Vdc) 4.35 3.80	Hz 88 83 46	ppm 0.050794 0.047908 0.026551	±2.5	Pass
25 Reference F	(Vdc) 4.35 3.80 3.14 Frequency: LTE Band	Hz 88 83 46 4(20MHz) Middle	ppm 0.050794 0.047908 0.026551	±2.5 channel=1732.50	Pass MHz
25	(Vdc) 4.35 3.80 3.14 requency: LTE Band Power supplied	Hz 88 83 46 4(20MHz) Middle	ppm 0.050794 0.047908 0.026551 channel=20175	±2.5	Pass
25 Reference F	(Vdc) 4.35 3.80 3.14 Frequency: LTE Band	Hz 88 83 46 4(20MHz) Middle Frequel	ppm 0.050794 0.047908 0.026551 channel=20175	±2.5 channel=1732.50	Pass MHz
25 Reference F	(Vdc) 4.35 3.80 3.14 requency: LTE Band Power supplied (Vdc)	Hz 88 83 46 4(20MHz) Middle Freque	ppm 0.050794 0.047908 0.026551 channel=20175 ncy error ppm	±2.5 channel=1732.50	Pass MHz





LTE Band 4(16QAM):

		LIE Band 4(16	QAIVI).		
Reference F	requency: LTE Band	4(1.4MHz) Middle	e channel=20175	channel=1732.50	MHz
Temperature $(^{\circ}\!$	Power supplied	ied Frequency error			_
	(Vdc)	Hz	ppm	Limit (ppm)	Result
25	4.35	83	0.047908	±2.5	Pass
	3.80	62	0.035786		
	3.14	72	0.041558		
Reference I	Frequency: LTE Band	d 4(3MHz) Middle	channel=20175	channel=1732.50N	ИHz
	Power supplied	Freque	ncy error		Result
Temperature (°C)	(Vdc)	Hz	ppm	Limit (ppm)	
	4.35	78	0.045022		Pass
25	3.80	43	0.024820	±2.5	
	3.14	69	0.039827		
Reference I	Frequency: LTE Band	d 4(5MHz) Middle	channel=20175	channel=1732.50N	ИHz
Temperature (°C)	Power supplied	Frequency error			
	(Vdc)	Hz	ppm	Limit (ppm)	Result
25	4.35	86	0.049639	±2.5	Pass
	3.80	88	0.050794		
	3.14	63	0.036364		
Reference F	requency: LTE Band	4(10MHz) Middle	channel=20175	channel=1732.50I	MHz
Temperature (°C)	Power supplied	Frequency error			
	(Vdc)	Hz	ppm	Limit (ppm)	Result
25	4.35	78	0.045022	±2.5	Pass
	3.80	89	0.051371		
	3.14	43	0.024820		
Reference F	requency: LTE Band	4(15MHz) Middle	•	channel=1732.50l	MHz
Temperature (℃)	Power supplied	Frequency error			
	(Vdc)	Hz	ppm	Limit (ppm)	Result
25	4.35	64	0.036941	±2.5	Pass
	3.80	80	0.046176		
	3.14	46	0.026551		
Reference F	requency: LTE Band	4(20MHz) Middle		channel=1732.50l	MHz
Temperature (℃)	Power supplied	Freque	ncy error	y error	
	(Vdc)	Hz	ppm	Limit (ppm)	Result
25	4.35	88	0.050794		
	3.80	72	0.041558	±2.5	Pass
					F 099
	3.14	78	0.041556		Pass